

Parameter	Value
$V_{CEO}$	50V
$I_C$	100mA
R	47k $\Omega$

### ●Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Complementary PNP Types :DTA144G series
- 5) Lead Free/RoHS Compliant.

### ●Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

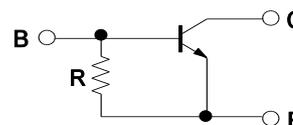
### ●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTC144GE	EMT3	1616	TL	180	8	3,000	K26
DTC144GUA	UMT3	2021	T106	180	8	3,000	K26
DTC144GKA	SMT3	2928	T146	180	8	3,000	K26

### ●Outline

<p>EMT3</p> <p>DTC144GE SOT-416 (SC-75A)</p>	<p>UMT3</p> <p>DTC144GUA SOT-323 (SC-70)</p>
<p>SMT3</p> <p>DTC144GKA SOT-346 (SC-59)</p>	

### ●Inner circuit



●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	$V_{CEO}$	50	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	100	mA
Collector Power dissipation	$P_C^{*2}$	200	mW
Junction temperature	$T_j$	150	°C
Range of storage temperature	$T_{stg}$	-55 to +150	°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	$BV_{CBO}$	$I_C = 50\mu A$	50	-	-	V
Collector-emitter breakdown voltage	$BV_{CEO}$	$I_C = 1mA$	50	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	$I_E = 160\mu A$	5	-	-	V
Collector cut-off current	$I_{CBO}$	$V_{CB} = 50V$	-	-	0.5	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 4V$	65	-	130	$\mu A$
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C / I_B = 10mA / 0.5mA$	-	-	0.3	V
DC current gain	$h_{FE}$	$V_{CE} = 5V, I_C = 5mA$	68	-	-	-
Emitter-base resistance	R	-	32.9	47	61.1	k $\Omega$
Transition frequency	$f_T^{*1}$	$V_{CE} = 10V, I_E = -5mA,$ $f = 100MHz$	-	250	-	MHz

\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference footprint

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Grounded emitter propagation characteristics

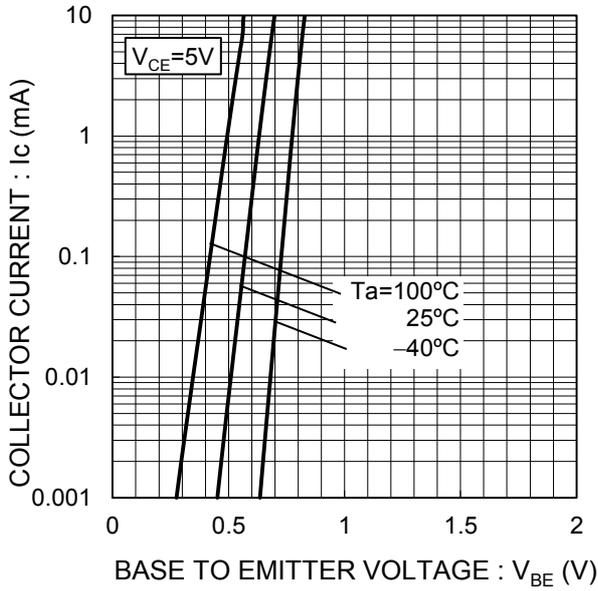


Fig.2 Grounded emitter output characteristics

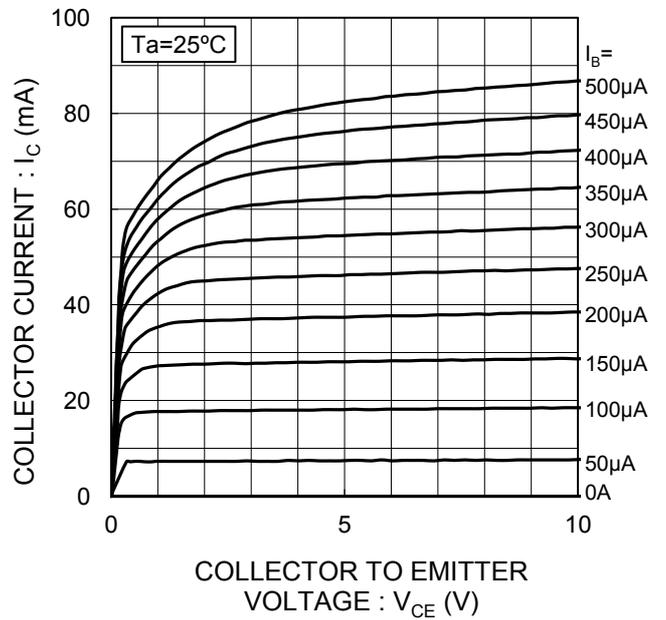


Fig.3 DC Current gain vs. Collector Current

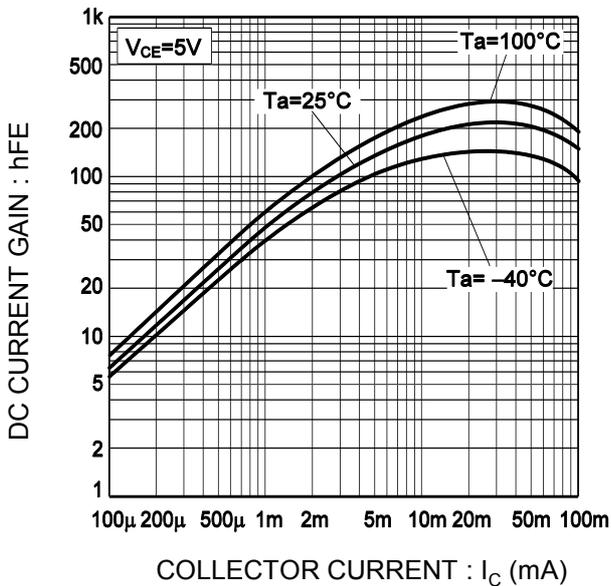
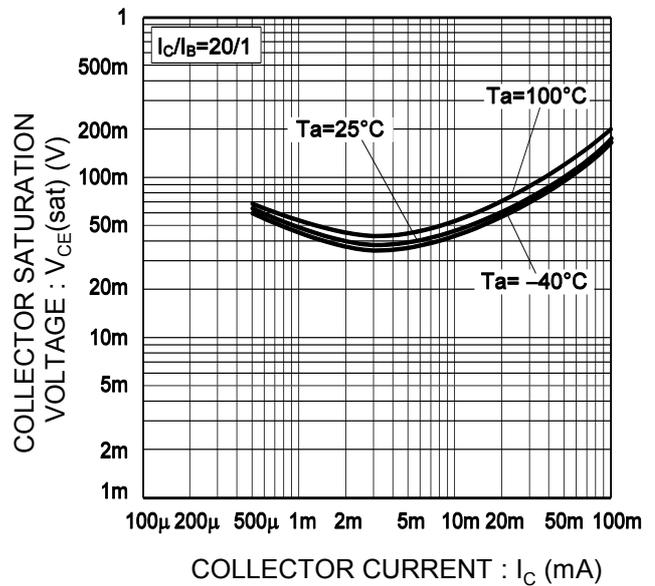
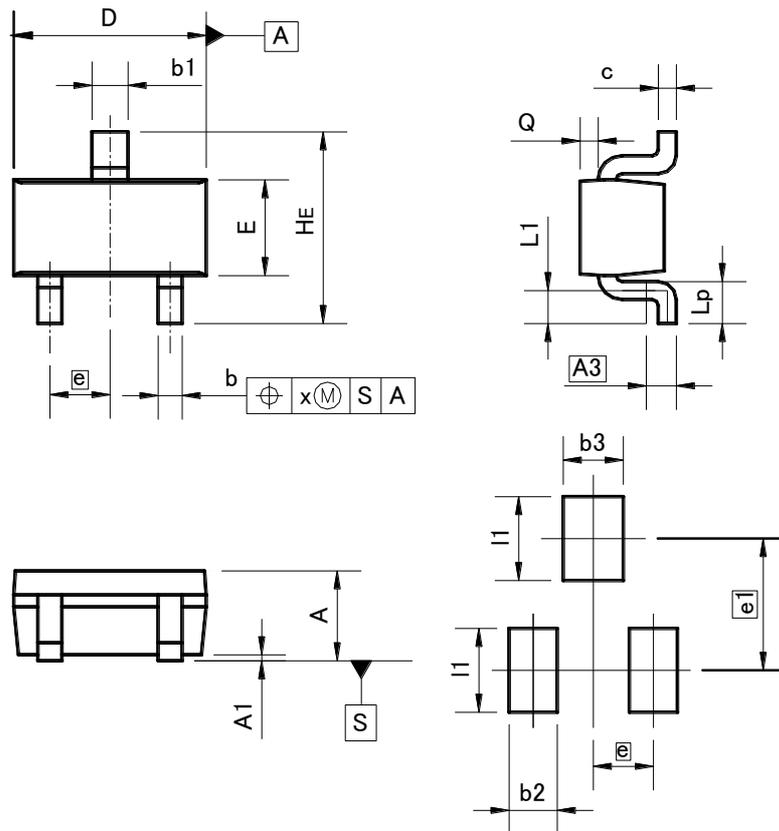


Fig.4 Collector-emitter saturation voltage vs. Collector Current



●Dimensions (Unit : mm)

EMT3



Pattern of terminal position areas

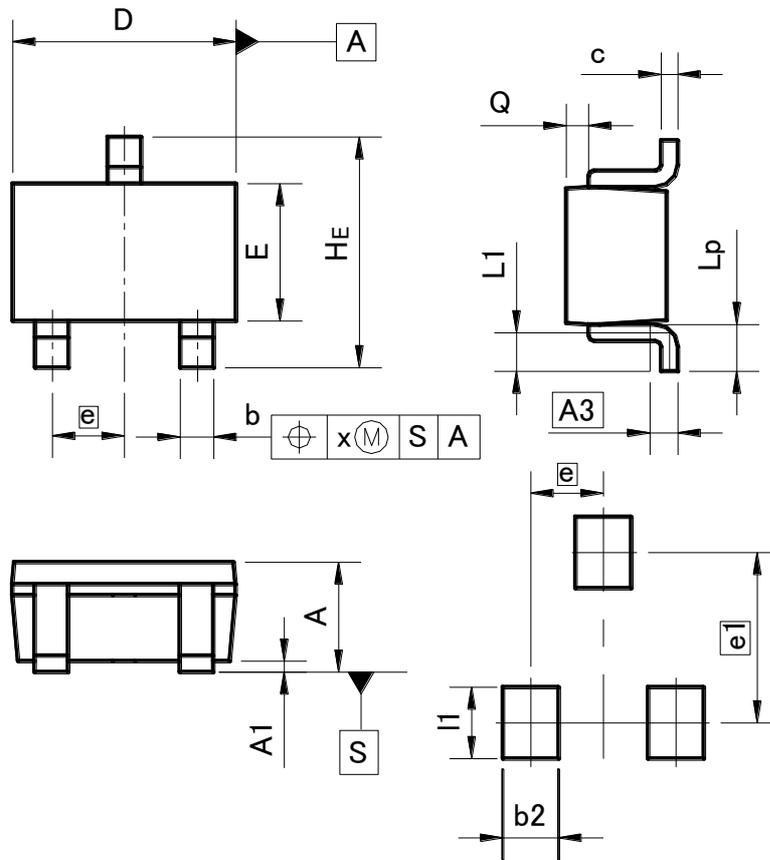
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.60	0.80	0.024	0.031
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.01	0.016
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
e	0.50		0.02	
HE	1.40	1.80	0.055	0.071
L1	0.10	-	0.004	-
Lp	0.15	-	0.006	-
Q	0.05	0.25	0.002	0.01
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.10		0.04	
b2	-	0.40	-	0.016
b3	-	0.50	-	0.02
l1	-	0.70	-	0.028

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT3



Pattern of terminal position areas

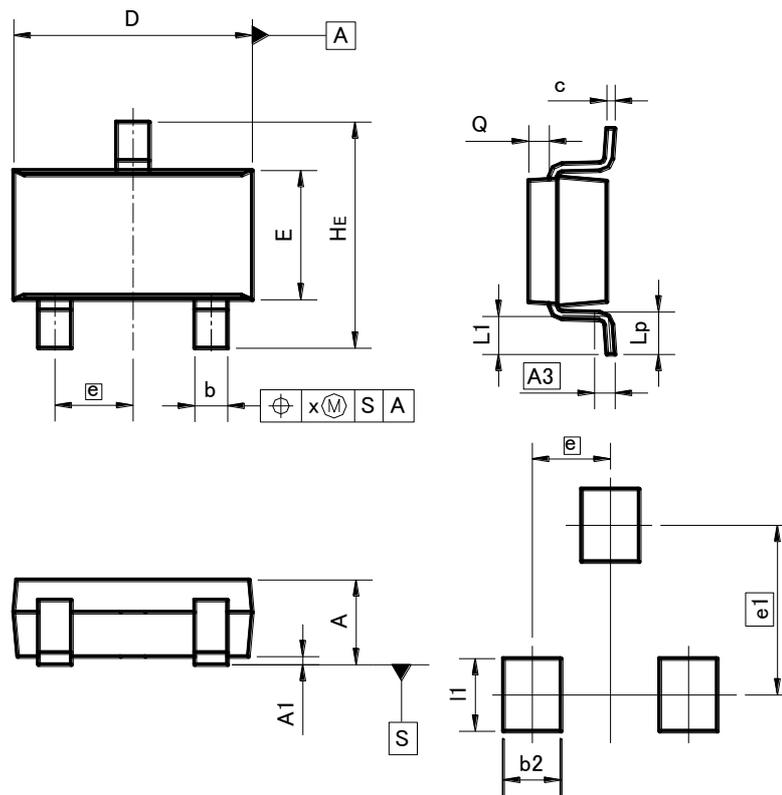
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.55		0.06	
b2	-	0.50	-	0.02
I1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT3



Pattern of terminal position areas

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	-	0.051
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.35	0.50	0.014	0.02
c	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	2.10		0.08	
b2	-	0.60	-	0.024
h	-	0.90	-	0.035

Dimension in mm/inches

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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9